

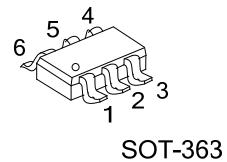
# 2N7002DW

**Power MOSFET**

**300mA, 60V DUAL  
N-CHANNEL POWER MOSFET**

## ■ DESCRIPTION

The UTC **2N7002DW** uses advanced technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with low gate voltages. This device is suitable for use as a load switch or in PWM applications.

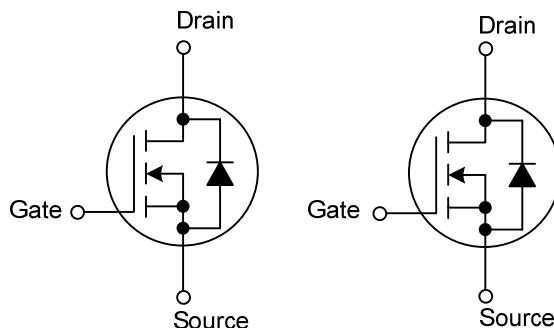


SOT-363

## ■ FEATURES

- \* High Density Cell Design for Low  $R_{DS(ON)}$
- \* Voltage Controlled Small Signal Switch
- \* Rugged and Reliable
- \* High Saturation Current Capability

## ■ SYMBOL



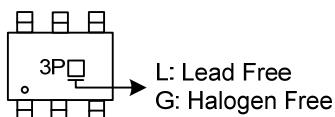
## ■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment						Packing
Lead Free	Halogen Free		1	2	3	4	5	6	
2N7002DWL-AL6-R	2N7002DWG-AL6-R	SOT-363	S1	G1	D2	S2	G2	D1	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

2N7002DWG-AL6-R 	(1)Packing Type	(1) R: Tape Reel  (2) Package Type  (3) Green Package
	(2)Package Type	
	(3)Green Package	

## ■ MARKING



■ ABSOLUTE MAXIMUM RATINGS ( $T_A=25^\circ\text{C}$ , unless otherwise noted.)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		$V_{DSS}$	60	V
Drain-Gate Voltage ( $R_{GS} \leq 1\text{M}\Omega$ )		$V_{DGR}$	60	V
Gate Source Voltage	Continuous	$V_{GSS}$	$\pm 20$	V
	Non Repetitive( $t_P < 50\mu\text{s}$ )		$\pm 40$	
Drain Current	Continuous	$I_D$	300	mA
	Pulsed		800	
Power Dissipation		$P_D$	200	mW
Derated Above $25^\circ\text{C}$			1.6	$\text{mW}/^\circ\text{C}$
Junction Temperature		$T_J$	+ 150	$^\circ\text{C}$
Storage Temperature		$T_{STG}$	-55 ~ +150	$^\circ\text{C}$

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	$\theta_{JA}$	625 (Note1)	$^\circ\text{C}/\text{W}$

■ ELECTRICAL CHARACTERISTICS ( $T_A=25^\circ\text{C}$ , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0\text{V}, I_D=10\mu\text{A}$	60			V
Drain-Source Leakage Current	$I_{DSS}$	$V_{DS}=60\text{V}, V_{GS}=0\text{V}$			1	$\mu\text{A}$
Gate-Source Leakage Current	$I_{GSSF}$	$V_{GS}=20\text{V}, V_{DS}=0\text{V}$			100	nA
	$I_{GSSR}$	$V_{GS}=-20\text{V}, V_{DS}=0\text{V}$			-100	nA
<b>ON CHARACTERISTICS (Note 2)</b>						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{GS}=V_{DS}, I_D=250\mu\text{A}$	1	2.1	2.5	V
Drain-Source On-Voltage	$V_{DS(\text{ON})}$	$V_{GS}=10\text{V}, I_D=300\text{mA}$		0.6	3.75	V
		$V_{GS}=5.0\text{V}, I_D=50\text{mA}$		0.09	1.5	
Static Drain-Source On-Resistance	$R_{DS(\text{ON})}$	$V_{GS}=10\text{V}, I_D=300\text{mA}$			2.0	$\Omega$
		$V_{GS}=10\text{V}, I_D=300\text{mA}, T_J=125^\circ\text{C}$			4.0	$\Omega$
		$V_{GS}=5.0\text{V}, I_D=50\text{mA}$			3.0	$\Omega$
<b>DYNAMIC CHARACTERISTICS</b>						
Input Capacitance	$C_{ISS}$	$V_{DS}=25\text{V}, V_{GS}=0\text{V}, f=1.0\text{MHz}$		20	50	pF
Output Capacitance	$C_{OSS}$			11	25	pF
Reverse Transfer Capacitance	$C_{RSS}$			4	5	pF
Turn-On Time	$t_{ON}$	$V_{DD}=30\text{V}, R_L=150\Omega$ $I_D=200\text{mA}, V_{GS}=10\text{V}$ $R_{GEN}=25\Omega$			20	nS
Turn-Off Time	$t_{OFF}$	$V_{DD}=30\text{V}, R_L=25\Omega$ $I_D=200\text{mA}, V_{GS}=10\text{V}$ $R_{GEN}=25\Omega$			20	nS
<b>DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS</b>						
Drain-Source Diode Forward Voltage	$V_{SD}$	$V_{GS}=0\text{V}, I_S=300\text{mA}$ (Note )		0.88	1.5	V
Maximum Pulsed Drain-Source Diode Forward Current	$I_{SM}$				0.8	A
Maximum Continuous Drain-Source Diode Forward Current	$I_S$				300	mA

Note: 1. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch. Minimum land pad size.

2. Pulse Test: Pulse Width≤300μs, Duty Cycle≤2.0%

## ■ TEST CIRCUIT AND WAVEFORM

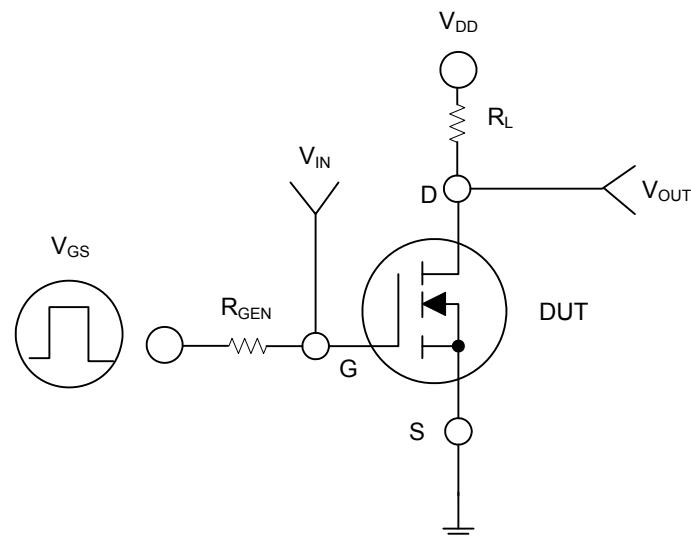


Fig. 1

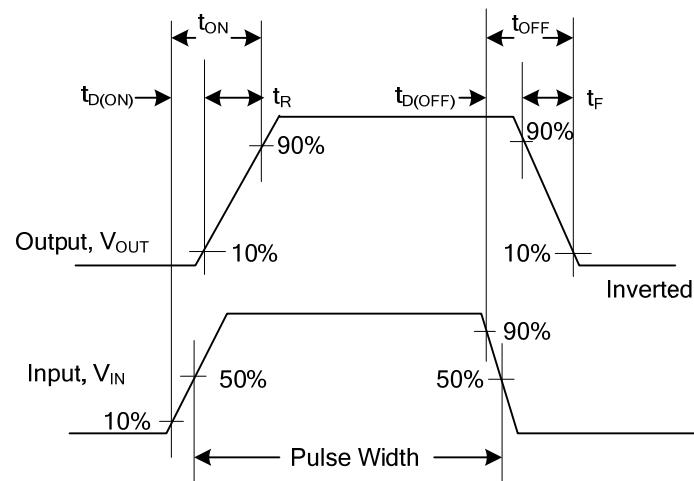
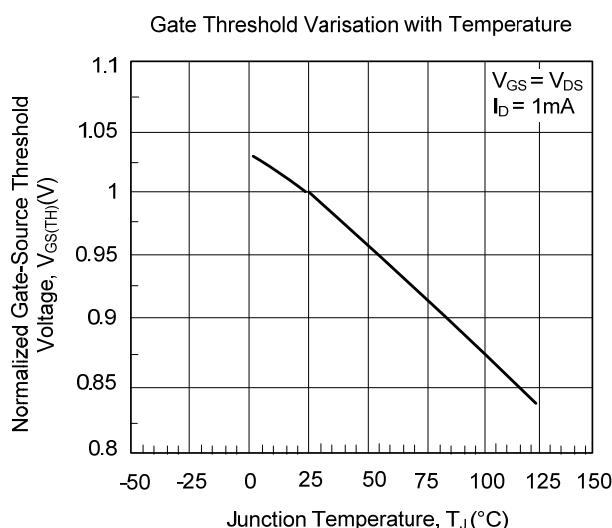
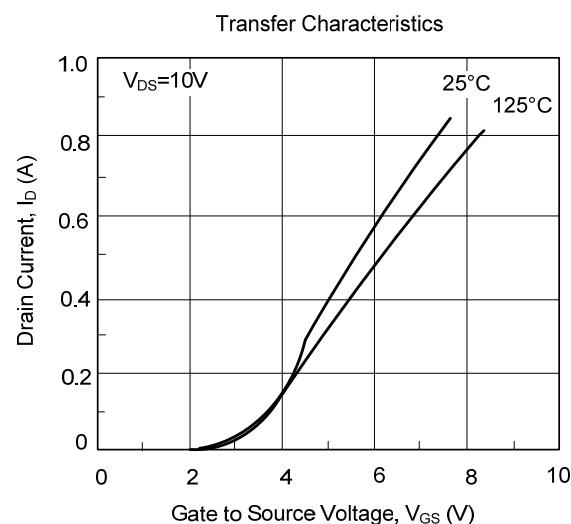
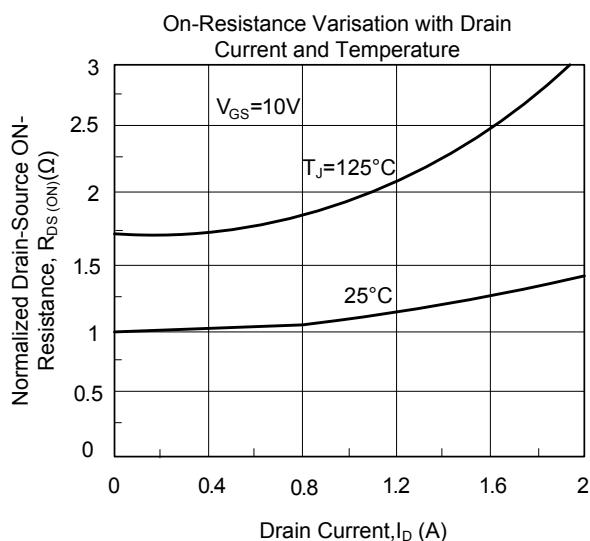
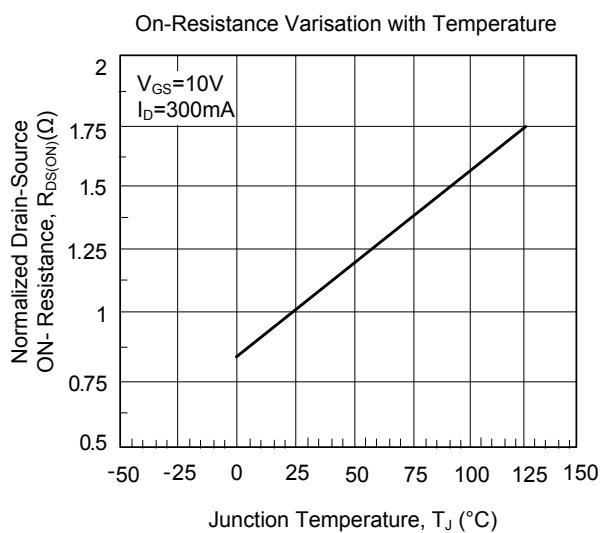
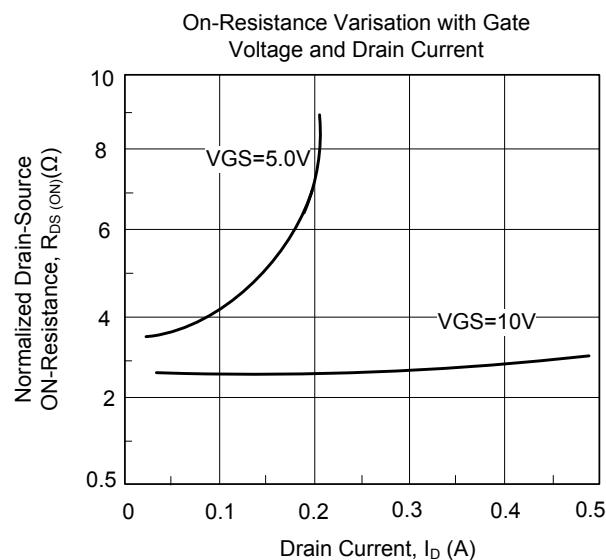
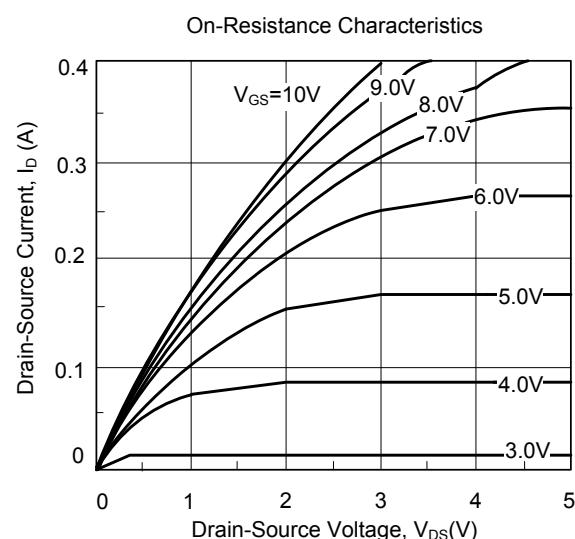
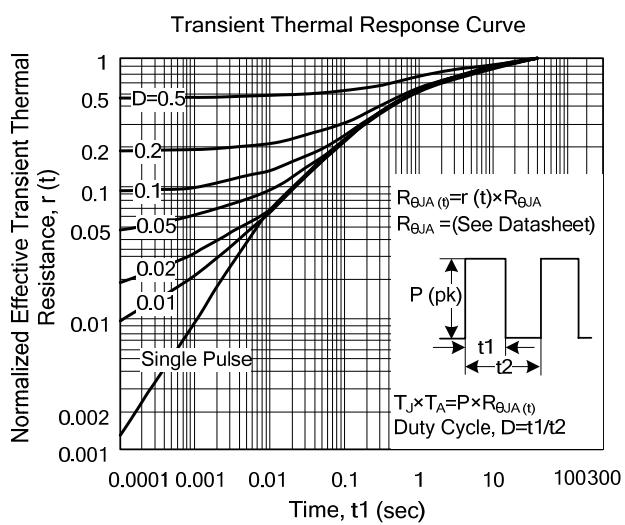
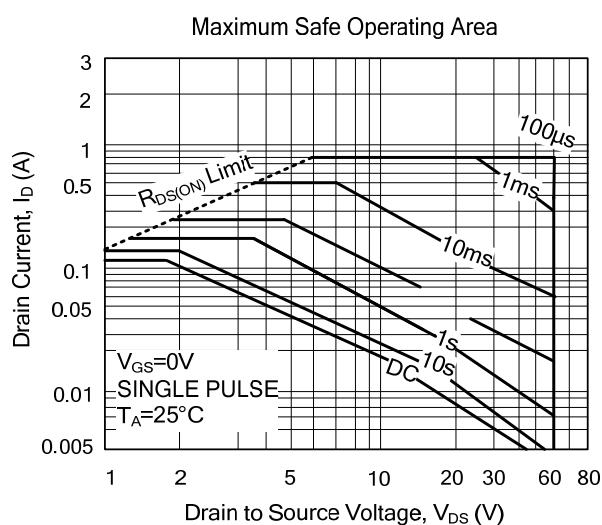
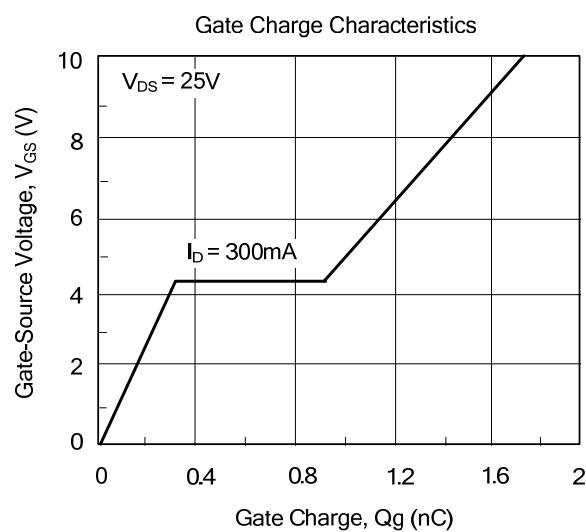
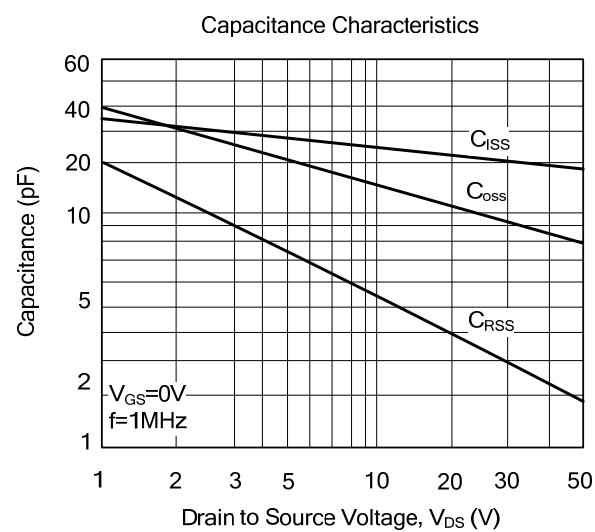
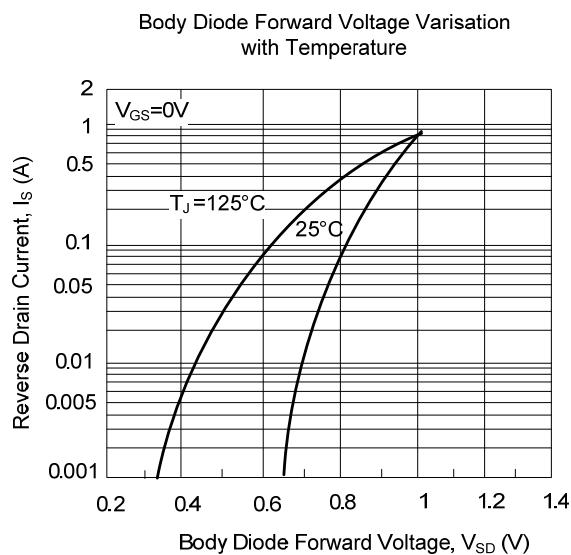
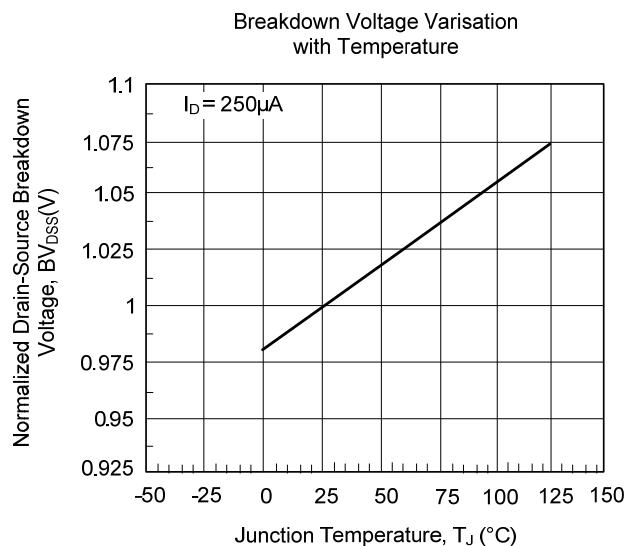


Fig. 2 Switching Waveforms

■ TYPICAL CHARACTERISTICS



## ■ TYPICAL CHARACTERISTICS (Cont.)



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